



P-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

V _{(BR)DSS}	R _{DS(ON)} max	I _D max T _A = +25°C
2014	75mΩ @ V_{GS} = -4.5V	-3.3A
-20V	140mΩ @ V _{GS} = -1.8V	-2.4A

Description and Applications

This MOSFET has been designed to minimize the on-state resistance (R_{DS(on)}) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

- Battery Charging
- Power Management Functions
- DC-DC Converters
- Portable Power Adaptors

Features and Benefits

- Low On-Resistance
- Very Low Gate Threshold Voltage V_{GS(th)} ≤ 1V
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q 101 Standards for High Reliability

Mechanical Data

- Case: SOT23
- Case Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals Connections: See Diagram Below
- Terminals: Finish Matte Tin annealed over Copper leadframe. Solderable per MIL-STD-202, Method 208
- Weight: 0.008 grams (approximate)

SOT23

Ordering Information (Note 4)

Part Number	Case	Packaging
DMP2160U-7	SOT23	3000/Tape & Reel

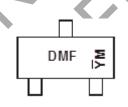
Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html

Marking Information



D	MF	M
		Γ

DMF = Marking Code YM = Date Code Marking for SAT (Shanghai Assembly/ Test site) $\overline{Y}M$ = Date Code Marking for CAT (Chengdu Assembly/ Test site) Y or \overline{Y} = Year (ex: A = 2013) M = Month (ex: 9 = September)

Chengdu A/T Site

Shanghai A/T Site

Date Code Key

Year	2008		2009	2010		2011	2012		2013	2014		2015
Code	V		W	Х		Y	Z		А	В		С
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Units	
Drain-Source Voltage	V _{DSS}	-20	V	
Gate-Source Voltage		V _{GSS}	±12	V
Continuous Drain Current (Note 5) V_{GS} = -4.5V	$T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$	ID	-3.3 -2.6	А
Pulsed Drain Current		I _{DM}	-13	А

Thermal Characteristics

Characteristic	Symbol	Value	Units
Total Power Dissipation (Note 5)	PD	1.4	W
Thermal Resistance, Junction to Ambient (Note 5)	R _{θJA}	90	°C/W
Thermal Resistance, Junction to Case (Note 5)	R _{ejc}	22	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	D°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

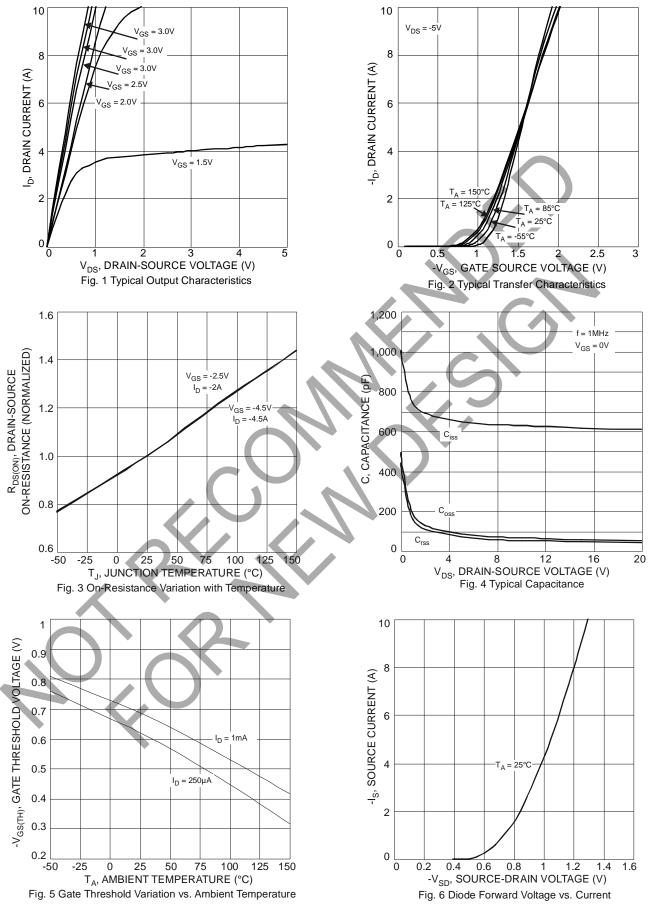
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 6)	Symbol	WILLI	чур	Wax	Unit	rest condition
Drain-Source Breakdown Voltage	BV _{DSS}	-20			V	V _{GS} = 0V, I _D = -250µA
Zero Gate Voltage Drain Current $T_J = +25^{\circ}C$	IDSS	-		-1.0	μA	$V_{DS} = -16V, V_{GS} = 0V$
Gate-Source Leakage	Igss	_		±100 ±800	nA	$V_{GS} = \pm 8V, V_{DS} = 0V$ $V_{GS} = \pm 12V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 6)						
Gate Threshold Voltage	V _{GS(th)}	-0.4	-0.6	-0.9	V	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$
			60	75		V _{GS} = -4.5V, I _D = -1.5A
Static Drain-Source On-Resistance	RDS (ON)	_	73	96	mΩ	$V_{GS} = -2.5V, I_D = -1.2A$
			92	140		V _{GS} = -1.8V, I _D = -1.2A
Forward Transconductance	<u>gfs</u>	-	7		S	V _{DS} = -10V, I _D = -1.5A
Diode Forward Voltage (Note 5)	Vsd			-1.0	V	$V_{GS} = 0V, I_{S} = -1.0A$
DYNAMIC CHARACTERISTICS (Note 7)				-	-	
Input Capacitance	Ciss	_	627	_	pF	
Output Capacitance	Coss	_	64		pF	V _{DS} = -10V, V _{GS} = 0V f = 1.0MHz
Reverse Transfer Capacitance	Crss	_	53	—	pF	1 - 1.000112
Gate Resistance	RG	_	44.9	—	Ω	$V_{GS} = 0V, V_{DS} = 0V, f = 1.0MHz$
Total Gate Charge	Qg	_	6.5	_	nC	
Gate-Source Charge	Q _{gs}	_	0.9	—	nC	$V_{GS} = -4.5V, V_{DS} = -10V, I_D = -3A$
Gate-Drain Charge	Q _{gd}		1.5	_	nC	
Turn-On Delay Time	t _{D(on)}		12.5		ns	
Turn-On Rise Time	tr	_	10.3	—	ns	$V_{DS} = -10V, V_{GS} = -4.5V,$
Turn-Off Delay Time	t _{D(off)}		46.5		ns	$R_L = 10\Omega, R_G = 1.0\Omega, I_D = -1A$
Turn-Off Fall Time	t _f		22.2		ns	

5. Device mounted on $1in^2$ FR-4 PCB with 2 oz. Copper. t ≤ 10 sec. Notes:

6. Short duration pulse test used to minimize self-heating effect.
7. Guaranteed by design. Not subject to product testing.

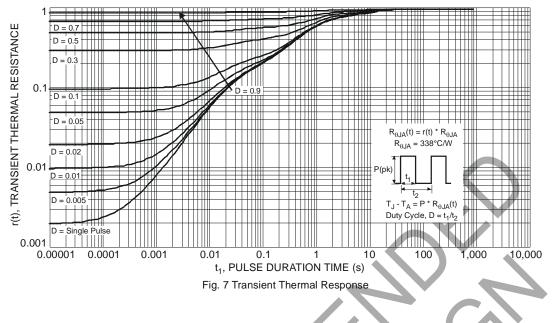


DMP2160U



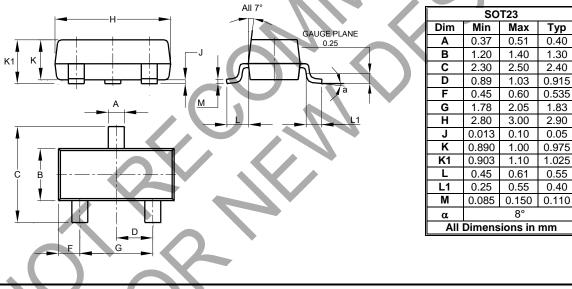
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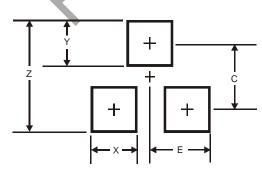
Package Outline Dimensions

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
Z	2.9
Х	0.8
Y	0.9
С	2.0
E	1.35



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